

# PNP General-Purpose Transistor

# **PN2907**

#### Description

This device is designed for use with general–purpose amplifiers and switches requiring collector currents to 500 mA.

These devices are Pb–Free, Halogen Free/BFR Free, Beryllium Free and are RoHS compliant.

# **ABSOLUTE MAXIMUM RATINGS** ( $T_A = 25^{\circ}C$ unless otherwise noted) (Note 1, 2)

Symbol	Parameter	Value	Unit	
V <sub>CEO</sub>			V	
V <sub>CBO</sub>			V	
V <sub>EBO</sub>	Emitter-Base Voltage	-5.0	V	
I <sub>C</sub>	I <sub>C</sub> Collector Current – Continuous		mA	
T <sub>J</sub> , T <sub>STG</sub>	Operating and Storage Junction Temperature Range	-55 to +150	°C	

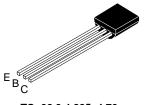
Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

- 1. These ratings are based on a maximum junction temperature of 150°C.
- These are steady-state limits. onsemi should be consulted on applications involving pulsed or low-duty cycle operations.

### THERMAL CHARACTERISTICS (T<sub>A</sub> = 25°C unless otherwise noted)

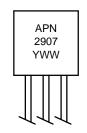
Symbol	Parameter	Max (Note 3)	Unit
P <sub>D</sub>	Total Device Dissipation	625	mW
	Derate Above 25°C	5.0	mW/°C
$R_{\theta JC}$	Thermal Resistance, Junction to Case	83.3	°C/W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	200	°C/W

3. PCB size: FR-4 76 x 114 x 1.57 mm³ (3.0 inch x 4.5 inch x 0.062 inch) with minimum land pattern size.



TO-92 3 4.825x4.76 CASE 135AN

#### MARKING DIAGRAM



PN2907 = Specific Device Code
A = Assembly Site
Y = Year of Production
WW = Work Week Number

#### **ORDERING INFORMATION**

See detailed ordering and shipping information on page 2 of this data sheet.

#### PN2907

## **ELECTRICAL CHARACTERISTICS** ( $T_A = 25^{\circ}C$ unless otherwise noted)

Symbol	Parameter	Conditions	Min	Max	Unit
OFF CHARA	ACTERISTICS		•		
V <sub>(BR)CEO</sub>	Collector–Emitter Breakdown Voltage (Note 4)	$I_C = -10 \text{ mA}, I_B = 0$	-40	_	V
V <sub>(BR)CBO</sub>	Collector-Base Breakdown Voltage	$I_C = -10 \mu A, I_E = 0$	-60	_	V
V <sub>(BR)EBO</sub>	Emitter-Base Breakdown Voltage	$I_E = -10 \mu A, I_C = 0$	-5.0	_	V
I <sub>CEX</sub>	Collector Cut-Off Current	$V_{CE} = -30 \text{ V}, V_{EB} = -0.5 \text{ V}$	-	-50	nA
I <sub>BL</sub>	Base Cut-Off Current	$V_{CE} = -30 \text{ V}, V_{EB} = -0.5 \text{ V}$	-	-50	nA
I <sub>CBO</sub>	Collector Cut-Off Current	$V_{CB} = -50 \text{ V}, I_E = 0$	-	-20	nA
		$V_{CB} = -50 \text{ V}, I_E = 0, T_A = 150^{\circ}\text{C}$	-	-20	μΑ
ON CHARAC	CTERISTICS (Note 4)				•
h <sub>FE</sub>	DC Current Gain	$V_{CE} = -10 \text{ V}, I_{C} = -0.1 \text{ mA}$	35	_	
		$V_{CE} = -10 \text{ V}, I_{C} = -1.0 \text{ mA}$	50	_	
		$V_{CE} = -10 \text{ V}, I_{C} = -10 \text{ mA}$	70	_	
		$V_{CE} = -10 \text{ V}, I_{C} = -150 \text{ mA}$	100	300	
		$V_{CE} = -10 \text{ V}, I_{C} = -500 \text{ mA}$	30	_	
V <sub>CE</sub> (sat)	Collector–Emitter Saturation Voltage	$I_C = -150 \text{ mA}, I_B = -15 \text{ mA}$	-	-0.4	V
		$I_C = -500 \text{ mA}, I_B = -50 \text{ mA}$	_	-1.6	
V <sub>BE</sub> (sat)	Base-Emitter Saturation Voltage	$I_C = -150 \text{ mA}, I_B = -15 \text{ mA}$	_	-1.3	V
		$I_C = -500 \text{ mA}, I_B = -50 \text{ mA}$	-	-2.6	
SMALL SIGI	NAL CHARACTERISTICS				
C <sub>ob</sub>	Output Capacitance	V <sub>CB</sub> = -10 V, f = 1.0 MHz	_	8	pF
C <sub>ib</sub>	Input Capacitance	V <sub>EB</sub> = -2.0 V, f = 1.0 MHz	-	30	pF
h <sub>fe</sub>	Small-Signal Current Gain	$I_C = -50 \text{ mA}, V_{CE} = -20 \text{ V}, f = 100 \text{ MHz}$	2	_	
SWITCHING	CHARACTERISTICS				
t <sub>on</sub>	Turn-On Time	$V_{CC} = -30 \text{ V}, I_C = -150 \text{ mA},$ $I_{B1} = -15 \text{ mA}$	_	45	ns
t <sub>d</sub>	Delay Time		-	10	ns
t <sub>r</sub>	Rise Time	7	-	40	ns
t <sub>off</sub>	Turn-Off Time	$V_{CC} = -6.0 \text{ V}, I_C = -150 \text{ mA},$	-	100	ns
ts	Storage Time	$I_{B1} = I_{B2} = -15 \text{ mA}$	_	80	ns
t <sub>f</sub>	Fall Time		-	30	ns

<sup>4.</sup> Pulse test: pulse width  $\leq 300~\mu s,$  duty cycle  $\leq 2.0\%.$ 

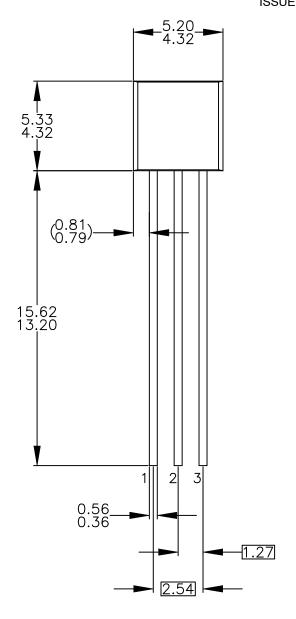
### **ORDERING INFORMATION**

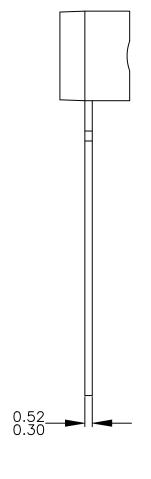
Part Number	Top Mark	Package	Shipping
PN2907BU	PN2907	TO-92 3 4.825x4.76 (Pb-Free)	10000 Units / Bulk

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

#### TO-92 3 4.825x4.76 CASE 135AN ISSUE O

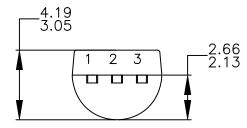
**DATE 31 JUL 2016** 





NOTES: UNLESS OTHERWISE SPECIFIED

- DRAWING WITH REFERENCE TO JEDEC TO-92 RECOMMENDATIONS. A)
- ALL DIMENSIONS ARE IN MILLIMETERS.
  DRAWING CONFORMS TO ASME Y14.5M—2009.



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Г	DESCRIPTION:	TO-92 3 4.825X4.76		PAGE 1 OF 1	

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